

The linearly scaling 3D fragment method for large scale electronic structure calculations

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Abstract. The Linear Scaling 3 dimensional fragment (LS3DF) method is an $O(N)$ *ab initio* electronic structure method for large scale nano material simulations. The main idea of this approach is divide-and-conquer, and the heart of this method is the novel patching scheme that effectively cancels out the artificial boundary effect, which exists in all divide-and-conquer schemes. This method has made *ab initio* simulations of the thousands-atom nano systems feasible in a couple of hours, while pertaining essentially the same accuracy as the direct calculation methods. The LS3DF method has won the Gordon Bell Prize in SC 2008 for its algorithmic achievement. The LS3DF code has reached 442 TFlops running on 147,456 processors on the Cray XT5 (Jaguar) at NCCS, and has been run on 163,840 processors on the Blue Gene/P (Intrepid) at ALCF, and has been applied to a system containing 36,000 atoms. In this paper, we will present the recent parallel performance results of this code, and will apply the method to the asymmetric CdSe/CdS core/shell nanorods, which have potential applications in electronic devices and solar cells.

1. Introduction

Nano structures have wide applications in the biological imaging, light emitting diodes, solar cells, and other electronic devices. The sizes of the nano structures are so small that they have very different electronic and optical properties, which have a strong dependence on the sizes of the nano structures (quantum confinement effect), from those of bulk materials. Nevertheless, to study the properties of nano structures, one needs do *ab initio* calculations on the systems containing 1,000 to 100,000 atoms, which are too large for the direct *ab initio* methods to simulate. Despite the increasing availability of the computer processors, the direct methods have been applied to systems with one or two thousand atoms at most [1]. This is because even the simplest *ab initio* methods - the density functional theory (DFT) methods under the local density approximation (LDA), are computationally expensive, scaling as $O(N^3)$, where N is the size of the system. In addition, due to the communication bottleneck the parallelization of the direct LDA methods might have a limit in the order of 10,000 processors [1]. In reality, the most widely used direct LDA code, VASP, is difficult to scale to thousands of processors. Therefore, both the computational costs and the limit on parallelization call for a change in the direct $O(N^3)$ algorithm. The $O(N)$ methods are required to simulate nano structures. Over the past decade,

many $O(N)$ methods have been developed [2]. These approaches can be classified to three main categories, the local orbital methods [3], the truncated D-matrix methods [4], and the divide and conquer methods [5]. While these methods have been able to successfully cut down the computational cost and have been applied to many larger systems, there exist some fundamental technical issues that are difficult to overcome. For example, in the commonly used local orbital methods, there exist extraneous local minima in the total energy functional, which make the total energy minimization difficult (convergence problem). This is due to constraining the wave functions on the local orbital manifold. Moreover, the overlap between neighbouring local orbitals has made these methods difficult to scale to the large number of processors. Some technical issues in the truncated density matrix methods (widely used in quantum chemistry) and the existing divide and conquer methods have been discussed in more detail in Ref. [7]. As a summary about the previous $O(N)$ methods, on top of some fundamental technical issues, the main challenge in these methods is to scale the codes to tens of thousands of computer processors while preserving the *ab initio* accuracy.

Recently we have developed a new $O(N)$ method, the linearly scaling 3 dimensional fragment (LS3DF) method [6,7]. It is a divide and conquer approach. It scales to tens of thousands of computer processors, and yields essentially the same results as the direct LDA methods. The LS3DF method has won the Gordon Bell Prize in SC 2008 for its algorithmic achievement [8]. In this paper, we will present the LS3DF method, focusing on its recent parallel performance results. Then we will apply the LS3DF method to study the electronic structures of the asymmetric CdSe/CdS core/shell nanorods, which have potential applications in the solar energy conversions.

2. The LS3DF method

The LS3DF method is based on the near-sightedness of quantum mechanical effects. The total energy of a system can be split into the classical electrostatic energy and the quantum mechanical energy (kinetic energy and exchange correlation energy). The electrostatic interaction is long-ranged, therefore the electrostatic energy must be calculated by globally solving the Poisson equation. But the quantum mechanical effect is short-ranged, therefore it can be solved locally, and then the quantum mechanical energy for the whole system can be obtained by combining the locally calculated quantum energies. In our LS3DF method, we divide a large system into small pieces (fragments), and independently calculate each fragment, then patch them together to obtain the total energy and the total charge density for the whole system. The heart of the LS3DF method is a novel patching scheme that effectively cancels out the artificial boundary effect. Figure 1 and 2 illustrate our division and patching scheme using a 2D example for simplicity. In Figure 1 a periodic super cell is divided into 4×4 pieces. At each grid point (i,j) , we introduce 4 fragments (along the right-upper direction) with different sizes, 1×1 , 2×1 , 1×2 and 2×2 . And then all fragments at all fragment grid point (i,j) ($i=1,\dots,4; j=1,\dots,4$) will be calculated independently using a direct LDA method, eg., PETot [9], a planewave pseudo potential

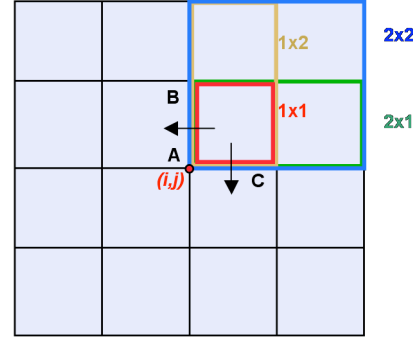


Fig. 1. A schematic view of the division of a system into small fragments. This 2D periodic super cell is divided into 4×4 fragment grids. At each fragment grid point (i,j) , 4 fragments with different sizes are introduced. Where the red, green, yellow, and blue rectangles represent the fragments of size 1×1 , 2×1 , 1×2 and 2×2 , respectively.

$$\text{Total} = \sum_{(i,j)} \left\{ \boxed{} - \boxed{} - \boxed{} + \boxed{} \right\}$$

Fig. 2. The schematic view of the fragment patching scheme in the LS3DF method for 2D systems. Here the yellow (1×2) and the green (2×1) fragments are negative fragments, and blue (2×2) and red (1×1) are positive fragments.

LDA code. Then, the fragments will be summed up according to the patching scheme illustrated in Figure 2. Where the 1x1 (red) and 2x2 (blue) fragments are positive fragments, and the other two, the 1x2 (yellow) and the 2x1 (green) are negative fragments.

We can demonstrate how the patching scheme recovers a system. Let's consider the area covered by the red square in Figure 1. For convenience, we denote the fragment 1x1 introduced at the fragment grid point (i,j) as $F_{11}(i,j)$. By counting how many positive and negative fragments cover this area, one can easily see whether this area is described properly after all the fragments are added up. This area is covered by 5 positive fragments, they are $F_{11}(i,j)$, $F_{22}(i-1,j-1)$, $F_{22}(i,j-1)$, $F_{22}(i,j)$ and $F_{22}(i-1,j)$. And this area is also covered by four negative fragments, which are $F_{21}(i,j)$, $F_{21}(i-1,j)$, $F_{12}(i,j)$ and $F_{12}(i,j-1)$. When these fragments are summed up using the patching scheme in Figure 2, the red square area will be covered only once after 4 positive and 4 negative fragments cancel out in pairs. We can also show the artificial boundary will be removed in this patching scheme. Let's consider the left boundary of the red square (edge AB). We can define a direction (outward) for this boundary as shown with a left arrow in Figure 1. We can count how many fragments go through this boundary. They are three positive fragments, $F_{11}(i,j)$, $F_{22}(i,j)$, and $F_{22}(i,j-1)$ and three negative fragments, $F_{12}(i,j)$, $F_{12}(i,j-1)$, and $F_{21}(i,j)$. When these six fragments are summed up, the edges from the three negative fragments will cancel out the edges from the other three positive fragments. As a result the edge (AB, outward) will disappear after the fragment summation. Similarly we can see the artificial corners (eg., the corner BAC, outward direction) will cancel out.

The patching scheme for 2D systems can be generalized to 3D systems straightforwardly. In 3D cases, at each fragment grid point (i,j,k) , eight fragments (along the right-upper direction) with different sizes will be introduced, they are four positive fragments, 2x2x2, 2x1x1, 1x2x1 and 1x1x2, and four negative fragments, 2x2x1, 2x1x2, 1x2x2, and 1x1x1. The patching scheme is

$$\text{Total} = \sum_{i,j,k} \{F_{222} + F_{211} + F_{121} + F_{112} - F_{221} - F_{212} - F_{122} - F_{111}\}$$

The presumption of this boundary effect cancellation is that the fragments that share a given boundary have very similar charge densities near that boundary. Our tests have shown that this presumption always holds as long as the smallest fragment (1x1x1) is not too small. When a typical 8-atom unit cell is chosen as the 1x1x1 fragments, the errors of the total energy, charge density, atomic force and the dipole moment are well under the common stopping criteria in the direct LDA methods. Thus the LS3DF method gives essentially the same results as the direct methods. In contrast to the convergence issues that is common in other $O(N)$ methods, the selfconsistent (SC) iterations in LS3DF converges at a comparable rate as the direct methods. For a system containing a few thousands atoms,

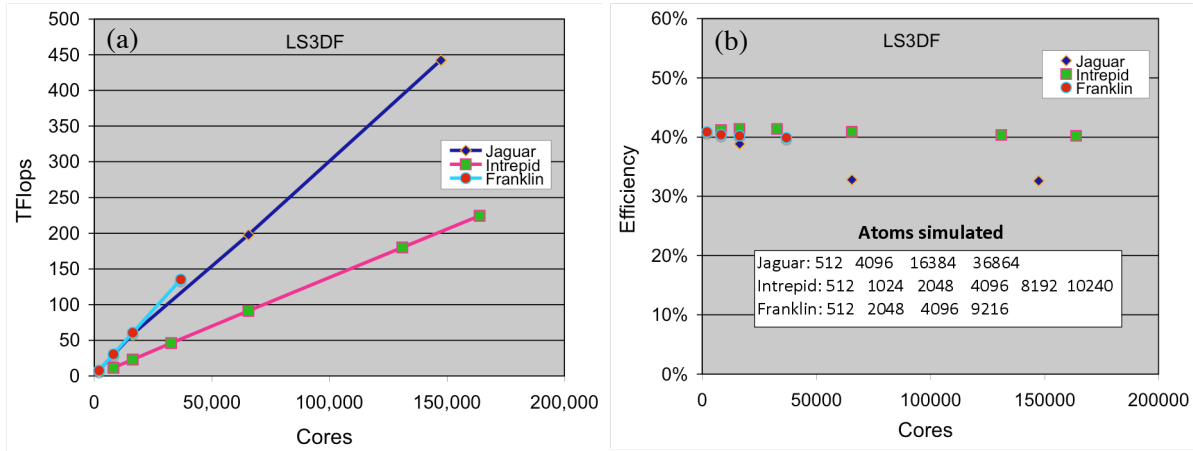


Fig. 3. Weak scaling floating point operation rates (a) and the computational efficiency (b) of the LS3DF method on different machines. The systems used were $\text{ZnTe}_{1-x}\text{O}_x$ alloy ($x=8\%$) with various number of atoms. The flops were measured for one SCF iteration step. The floating point operations were measured in the double precision, using the profiling tool Craypat 4.1.

the total energy typically converges to 10^{-6} a.u. within 50-60 iterations. The LS3DF method outperforms the direct LDA methods when the system contains more than 550 atoms. For nano structures with 10,000 atoms, the LS3DF would be faster by 3 orders of magnitudes, even presuming the direct LDA methods can scale up to thousands of processors. For more details about the LS3DF method, please refer to Ref. [6,7].

One of the great advantages of the LS3DF method is its excellent parallel scaling. We have run our code on the Cray XT4 (Franklin) at NERSC, the Cray XT5 (Jaguar) at NCCS, and the Blue Gene/P (Intrepid) at ALCF. Figure 3 shows the weak scaling results on these three machines. The LS3DF code has shown a linear scaling up to the maximum available processor cores on all three supercomputers. It has reached 135 Tflops on 36,864 cores on Franklin at 40% efficiency; 224 Tflops on 163,840 cores on Intrepid at 40% efficiency; 442 Tflops on 147,456 cores on Jaguar at 33% efficiency. For more previous performance results of the LS3DF method, see Ref. [9].

3. Electronic structure calculations for asymmetric CdSe/CdS core/shell nanorods

With the advance of the synthetic methods, more and more different shapes of nano structures have been synthesized in the labs. Recently Carbone and his colleagues have synthesized asymmetric core/shell structures, using newly developed seed growth method [10]. In the asymmetric core/shell nanorods, a CdSe core is embedded in one end of the cylindrical CdS shells. By changing the sizes of the core and the shell (both diameter and length), one can manipulate the electronic structures inside the nanorods. Hence these nano structures appear to be particularly interesting to solar cell applications. In addition, these asymmetric core/shell structures provide a system on which one can study the quantum confinement effect, the band alignment, the strain (due to the core/shell lattice constant mismatch), and the surface effects.

We have applied the LS3DF method to the asymmetric CdSe/CdS core/shell nanorods with the Cd terminated and the Cd+S terminated surfaces, respectively, and also to their counterparts, the pure CdS nanorods, to study how the core and the surface affect the electronic structures inside these nanorods. We have calculated the valence band maximum (VBM, hole) and the conduction band minimum (CBM, electron) states and the band gaps (Table 1), utilizing the folded spectrum method [11], and have also calculated the dipole moments (Table 2) of these nanorods. One can see that in the nanorods with the Cd terminated surface, the introduction of the CdSe core results in a significant change in the band gaps (0.24 eV) and dipole moment (-9.65 a.u.), while in the nanorods with the Cd+S terminated surfaces, the role of the CdSe core seems to be suppressed by the surface effect, and the band gap and the dipole moment changes are small. Figure 4 shows the charge density isosurface of the hole and the electron states of the four nanorods. One can see that in the nanorods with the Cd terminated surface the introduction of the CdSe core significantly changes the localization of the hole states, while in the nanorods with the Cd+S terminated surface, the hole state

| | Cd termin. (eV) | Cd+S termin. (eV) | Band gap change (eV) |
|-------------------------|--------------------|----------------------|-------------------------|
| Pure CdS nanorods | 2.655 | 2.498 | -0.156 |
| CdSe/CdS Core/shell | 2.415 | 2.403 | -0.011 |
| Band gap change (eV) | -0.240 | -0.095 | |

Table 1. The calculated band gaps of the four nanorods. The band gap changes due to the different surfaces (column 4) and the CdSe core (row 4) are also shown in the table.

| | Cd termin. (a.u.) | Cd+S termin. (a.u.) | Dipole mom. change (a.u.) |
|------------------------------|----------------------|------------------------|------------------------------|
| Pure CdS nanorods | -15.623 | -28.415 | -12.792 |
| CdSe/CdS core/shell | -25.277 | -28.108 | -2.830 |
| Dipole mom. change (a.u.) | -9.654 | 0.307 | |

Table 2. The calculated dipole moments along the c-axis of the four CdS nanorods (the components of the dipole moments in the other two directions are small, not shown here). The dipole moment changes due to the different surfaces (column 4), and the CdSe cores (row 4) are also shown in the table.

localization seems not be affected by the presence of the CdSe core, indicating the Cd+S terminated surface has the dominant effects to the hole localizations. For more details, see Ref. [12].

4. Conclusion

We have presented the LS3DF method for *ab initio* electronic structure calculations. We have described how the method works without going into the implementation details, and have presented the parallel scaling, and have summarized the accuracy and the SCF convergence rate. We have applied this method to the asymmetric CdSe/CdS core/shell nanorods, to study the electronic structures inside

these nano structures. As a summary, the LS3DF method is an $O(N)$ *ab initio* electronic structure code ; it scales linearly to hundreds of thousands of computer processors; it yields essentially the same results as the direct LDA methods; it can solve a nano system with thousands of atoms selfconsistently in a couple of hours. We expect it will find wide applications in nanostructure calculations.

Acknowledgments

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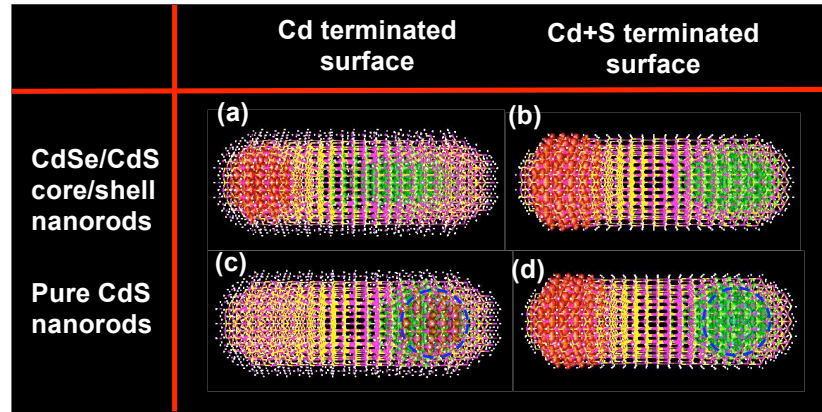


Figure 17. Isosurface of the charge densities of the conduction band minimum (CBM, green) and the valance band maximum (VBM, red) states of the four CdS nanorods with/without CdSe core. Where (a) and (b) are for the pure CdS nanorods with the Cd terminated and the Cd+S terminated surfaces, while (c) and (d) are for the corresponding CdSe/CdS core/shell nanorods, respectively. The isovalue larger than 0.001 e/bhor³ was shown for both VBM and CBM states. The blue dashed circle shows the CdSe core area. These nanorods are constructed as a wurzite structure, and have 2.8 nm in diameter, and 8.4 nm in length (c-axis). The diameter of the CdSe core is 2.1 nm. There are 3063 and 2298 atoms in the nanorods with the Cd terminated and the Cd+S terminated surfaces, respectively. Where the magenta, yellow, and blue dots represent the Cd, S, and Se atoms, respectively, and the white dots represent pseudo H atoms which passivate the surface dangling bonds.